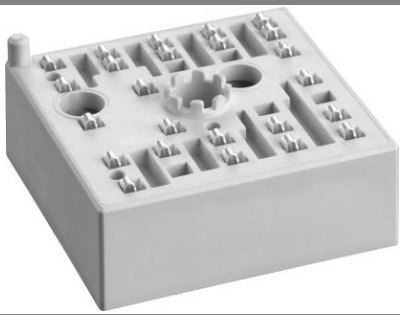


# SKiiP 12NAB12T4V1



MiniSKiiP® 1

3-phase bridge rectifier +  
brake chopper + 3-phase  
bridge inverter  
**SKiiP 12NAB12T4V1**

Preliminary Data

## Features

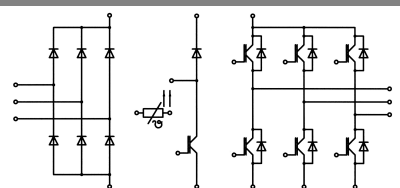
- Latest Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

## Typical Applications

- Inverter up to 10 kVA
- Typical motor power 5,5 kW

## Remarks

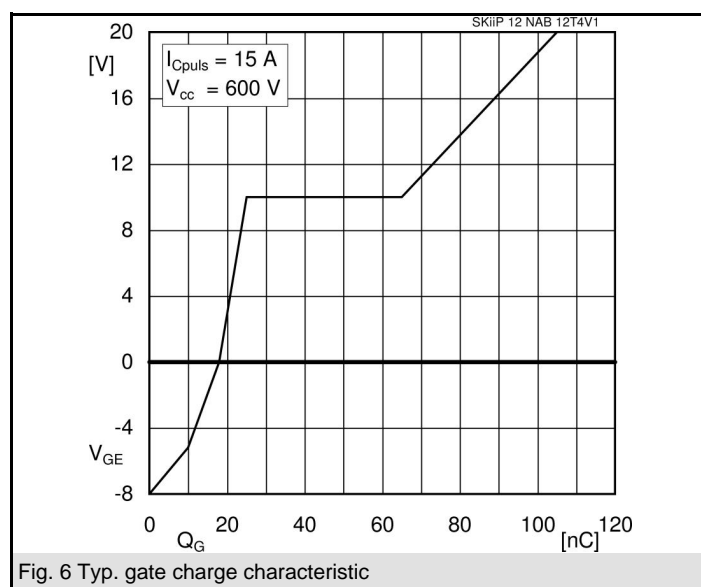
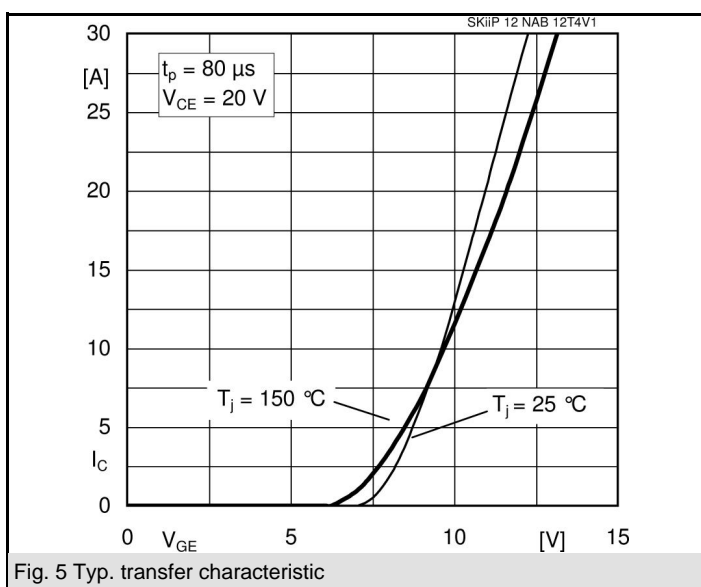
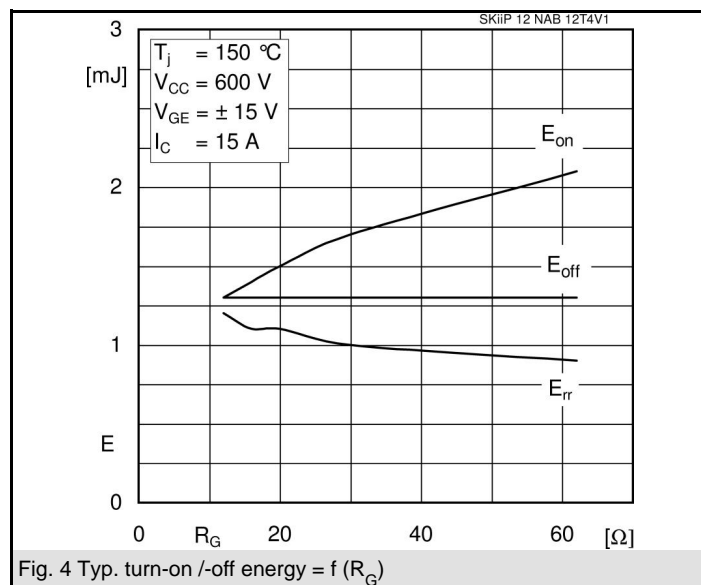
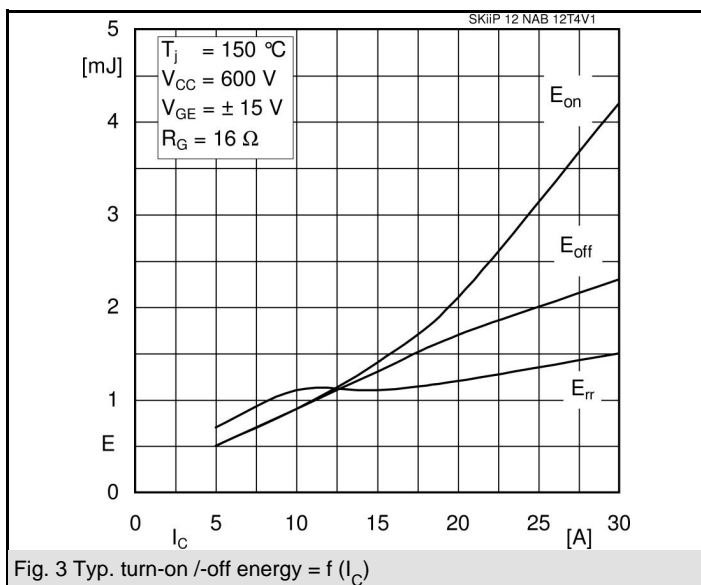
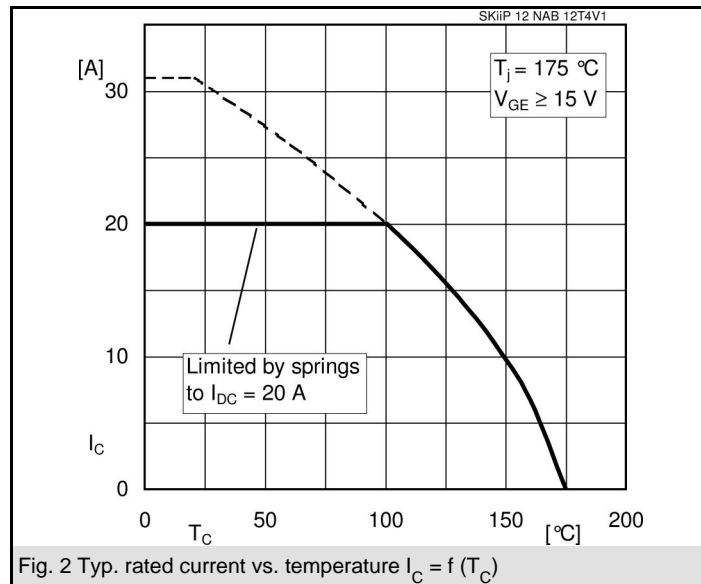
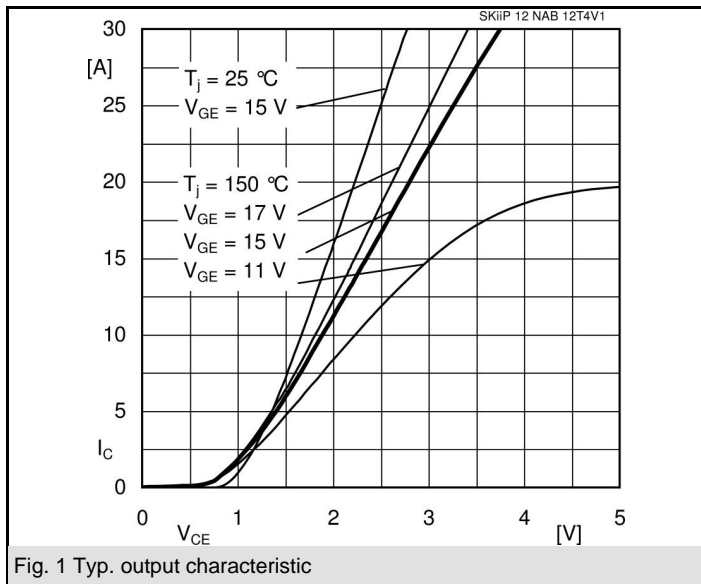
- $V_{CEsat}$ ,  $V_F$  = chip level value
- Case temperature limited to  $T_C = 125^\circ\text{C}$  max.
- recomm.  $T_{op} = -40 \dots +150^\circ\text{C}$
- product rel. results valid for  $T_j \leq 150$

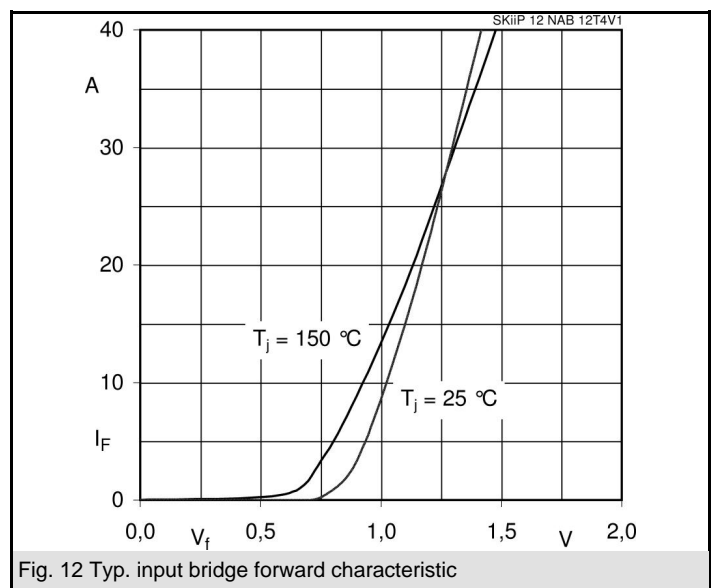
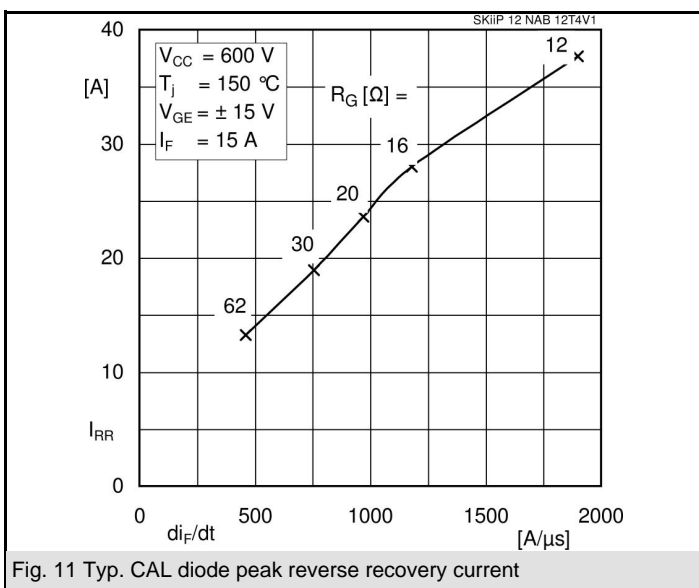
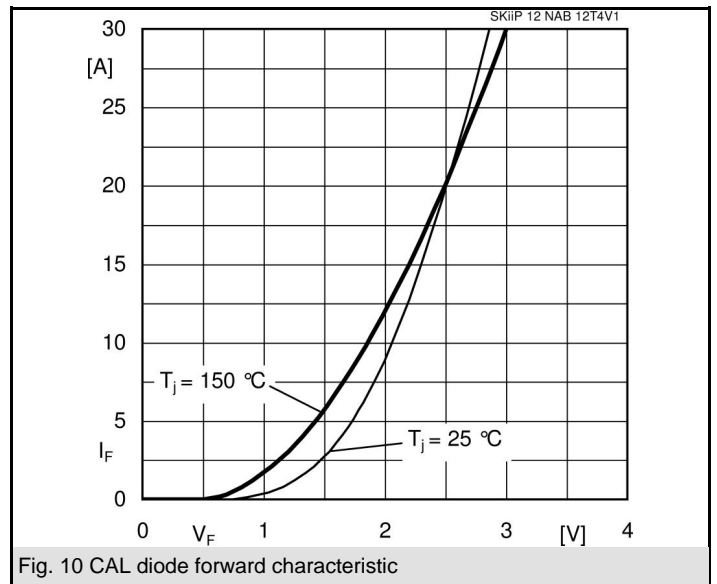
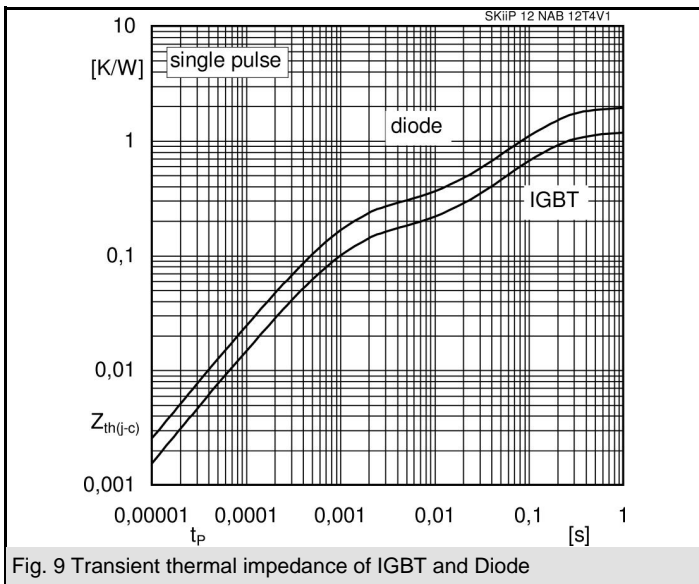
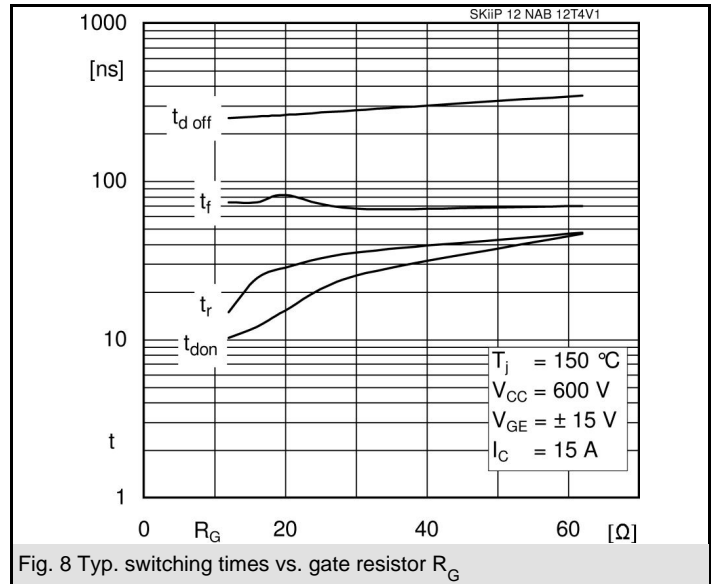
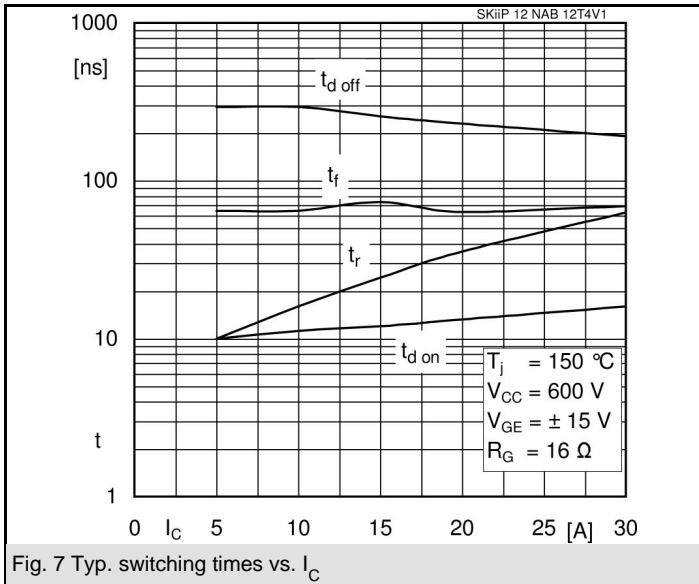


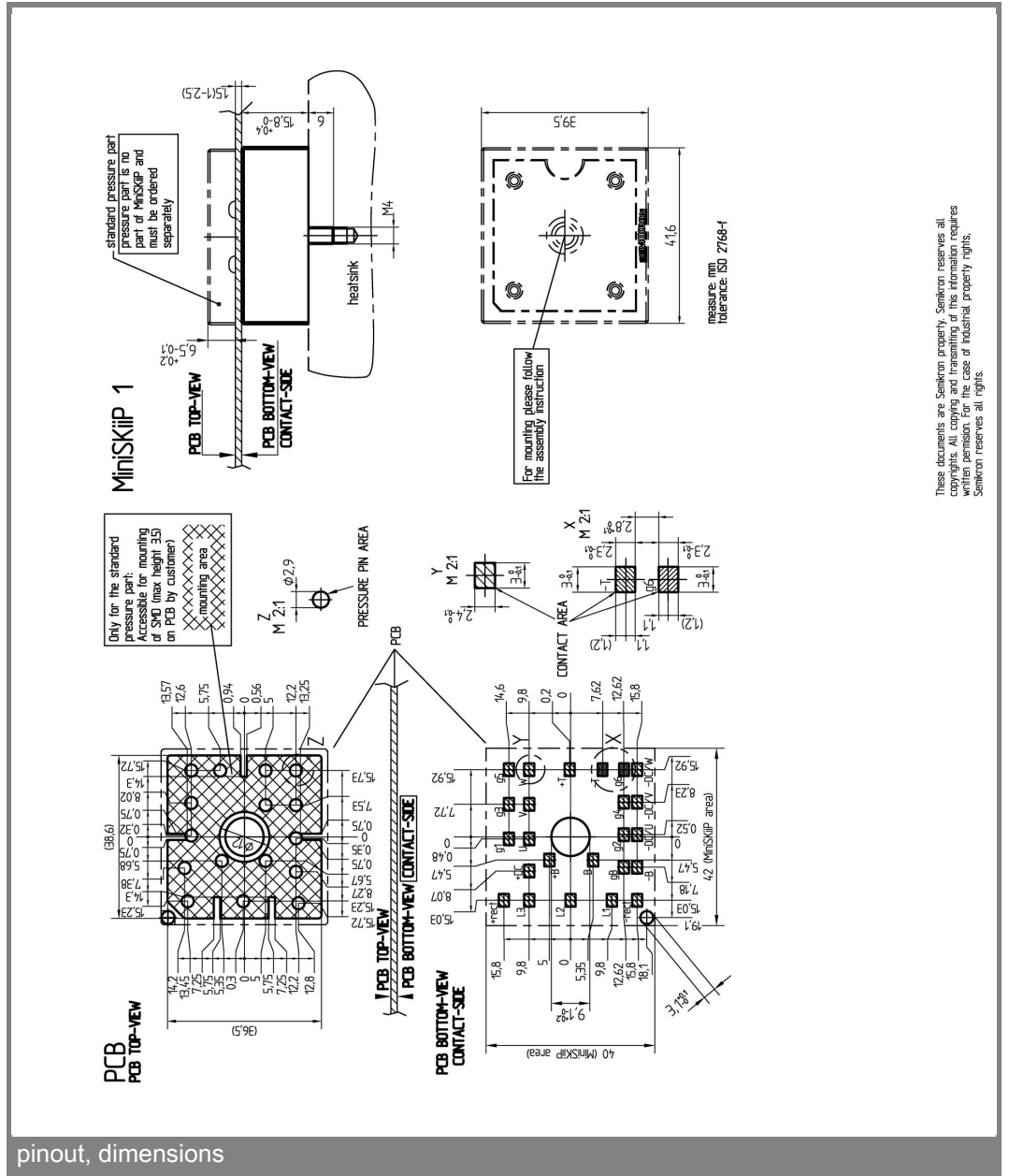
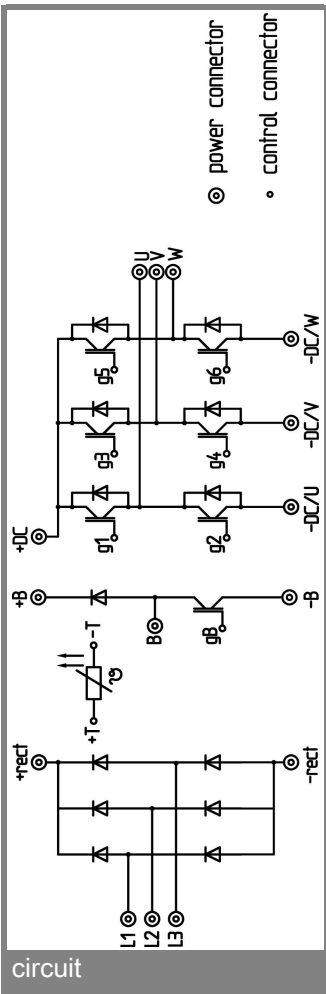
NAB

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter, Chopper</b>			
$V_{CES}$	$T_s = 25 (70)^\circ\text{C}$ $t_p \leq 1 \text{ ms}$	1200	V
$I_C$		31 (25)	A
$I_{CRM}$		45	A
$V_{GES}$		$\pm 20$	V
$T_j$		- 40 ... + 175	$^\circ\text{C}$
<b>Diode - Inverter, Chopper</b>			
$I_F$	$T_s = 25 (70)^\circ\text{C}$ $t_p \leq 1 \text{ ms}$	24 (19)	A
$I_{FRM}$		45	A
$T_j$		- 40 ... + 175	$^\circ\text{C}$
<b>Diode - Rectifier</b>			
$V_{RRM}$	$T_s = 70^\circ\text{C}$ $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$ $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$	1600	V
$I_F$		35	A
$I_{FSM}$		220	A
$i^2t$		240	$\text{A}^2\text{s}$
$T_j$		- 40 ... + 150	$^\circ\text{C}$
$I_{tRMS}$	per power terminal (20 A / spring)	20	A
$T_{stg}$		- 40 ... + 125	$^\circ\text{C}$
$V_{isol}$	AC, 1 min.	2500	V

Characteristics		$T_s = 25^\circ\text{C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter, Chopper</b>					
$V_{CEsat}$	$I_{Cnom} = 15 \text{ A}, T_j = 25 (150)^\circ\text{C}$		1,85 (2,25)	2,1 (2,5)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = \text{mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25 (150)^\circ\text{C}$		1,1 (1)	1,3 (1,2)	V
$r_T$	$T_j = 25 (150)^\circ\text{C}$		50 (83)	53 (87)	m $\Omega$
$C_{ies}$	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		900		nF
$C_{oes}$	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		80		nF
$C_{res}$	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		55		nF
$R_{th(j-s)}$	per IGBT		1,22		K/W
$t_{d(on)}$	under following conditions		15		ns
$t_r$	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		25		ns
$t_{d(off)}$	$I_{Cnom} = 15 \text{ A}, T_j = 150^\circ\text{C}$		260		ns
$t_f$	$R_{Gon} = R_{Goff} = 16 \Omega$		75		ns
$E_{on}$	inductive load		1,4		mJ
$E_{off}$			1,3		mJ
<b>Diode - Inverter, Chopper</b>					
$V_F = V_{EC}$	$I_{Fnom} = 15 \text{ A}, T_j = 25 (150)^\circ\text{C}$		2,2 (2,1)	2,5 (2,45)	V
$V_{(TO)}$	$T_j = 25 (150)^\circ\text{C}$		1,3 (0,9)	1,5 (1,1)	V
$r_T$	$T_j = 25 (150)^\circ\text{C}$		60 (80)	67 (90)	m $\Omega$
$R_{th(j-s)}$	per diode		2,02		K/W
$I_{RRM}$	under following conditions		28		A
$Q_{rr}$	$I_{Fnom} = 15 \text{ A}, V_R = 600 \text{ V}$		2,6		$\mu\text{C}$
$E_{rr}$	$V_{GE} = 0 \text{ V}, T_j = 150^\circ\text{C}$ $di_F/dt = 1180 \text{ A}/\mu\text{s}$		1,1		mJ
<b>Diode - Rectifier</b>					
$V_F$	$I_{Fnom} = 15 \text{ A}, T_j = 25^\circ\text{C}$		1,1		V
$V_{(TO)}$	$T_j = 150^\circ\text{C}$		0,8		V
$r_T$	$T_j = 150^\circ\text{C}$		20		m $\Omega$
$R_{th(j-s)}$	per diode		1,5		K/W
<b>Temperature Sensor</b>					
$R_{ts}$	3 %, $T_r = 25 (100)^\circ\text{C}$		1000(1670)		$\Omega$
<b>Mechanical Data</b>					
w			35		g
$M_s$	Mounting torque	2		2,5	Nm







These documents are Semikron property. Semikron reserves all rights in them. All other rights are reserved. Written permission for the case of industrial property rights. Semikron reserves all rights.

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.